



ORIENT

Photo coupler

Product Data Sheet

MPN: ORPC-817 series

Customer: _____

Date: _____

SHENZHEN ORIENT COMPONENTS CO ., LTD

Block A3rd Floor No.4 Building, Tian'an Cyber Park, Huangge Rd, LongGang Dist, Shenzhen, GD

TEL: 0755-29681817

FAX: 0755-29681200

www.orient-opto.com

Preliminary

This datasheet is a preliminary design specification, and the formal specifications are subject to the recognition letter with jointly signed

1. Features

- (1) Current transfer ratio (CTR : MIN. 50% at $I_F = 5mA$, $V_{CE} = 5V$)
- (2) High input-output isolation voltage ($V_{iso} = 5,000V_{rms}$)
- (3) Response time (t_r : TYP. $4\mu s$ at $V_{CE} = 2V$, $I_C = 2mA$, $R_L = 100\Omega$)
- (4) Operating Temperature $-55\text{ }^\circ C$ to $110\text{ }^\circ C$
- (5) ESD pass HBM 8000V/MM 2000V
- (6) Safety approval
 - UL approved (No.E323844)
 - VDE approved(No.40029733)
 - CQC approved (No.CQC09001029446)
 - CE approved (No.AC/0431008)
 - State Grid approved (No.SGCM013420240085)
- (7) In compliance with RoHS, REACH standards
- (8) MSL Class I



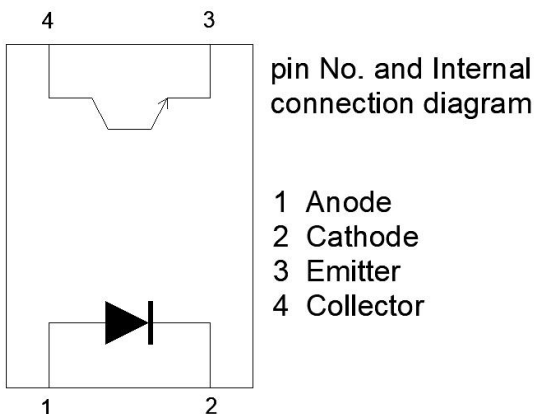
2. Description

- (1) ORPC-817 photo coupler consist of one piece of GaAs emitter and one piece of NPN transistor.
- (2) Packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

3. Applications

- (1) Switching power supply
- (2) Ammeter
- (3) Computer
- (4) Instrumental application, measurement machine
- (5) Signal transforming systems
- (6) Imbursement equipments, duplicating machine, automat
- (7) Family-use electric equipments, such as fans

4. Functional Diagram



5. Absolute Maximum Ratings at Ta=25°C

Parameter		Symbol	Rated Value	Unit
Input	Forward Current	I _F	60	mA
	Peak forward Current (100µs pulse, 100Hz frequency)	I _{FP}	1	A
	Reverse Voltage	V _R	6	V
	Consume Power	P	70	mW
Output	Collector and emitter Voltage	V _{CEO}	80	V
	Emitter and collector Voltage	V _{ECO}	7	
	Collector Current	I _C	50	mA
	Consume Power	P _C	150	mW
Total Consume Power		P _{tot}	200	mW
*1 Insulation Voltage		V _{iso}	5000	V _{rms}
Maximum transient isolation voltage (Insulating oil test)		V _{IOTM}	8000	V _{peak}
Maximum repetitive peak isolation voltage		V _{IORM}	850	V _{peak}
Operation Temperature		T _{opr}	-55 to + 110	°C
Storage Temperature		T _{stg}	-55 to + 125	
*2 Soldering Temperature		T _{sol}	260	

*1.AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. Soldering time is 10 seconds

6. Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Parameter		Symbol	Min	Typ.*	Max	Unit	Condition
Input	Forward Voltage	V _F	---	1.2	1.4	V	I _F =20mA
	Reverse Current	I _R	---	---	5	μA	V _R =5V
	Terminal capacitance	C _t	---	30	250	pF	V=0, f=1KHz
Output	Collector to Emitter Current	I _{CEO}	---	---	100	nA	V _{CE} =20V, I _F =0mA
	Collector and Emitter Breakdown Voltage	BV _{CEO}	80	---	---	V	I _C =0.1mA I _F =0mA
	Emitter and Collector Breakdown Voltage	BV _{ECO}	7	---	---	V	I _E =0.1mA I _F =0mA
Transforming Characteristics	*1 Current conversion ratio	CTR	50	---	600	%	I _F =5mA V _{CE} =5V
	Collector Current	I _C	2.5	---	30	mA	
	Collector and Emitter Saturation Voltage	V _{CE(sat)}	---	0.1	0.2	V	I _F =20mA I _C = 1mA
	Insulation Impedance	R _{iso}	5×10 ¹⁰	1×10 ¹²	---	Ω	DC500V 40~60%R.H.
	Floating Capacitance	C _f	---	0.6	1.0	pF	V=0, f=1MHz
	Rise Time	t _r	---	4	18	μs	V _{CE} =2V, I _C =2mA R _L =100Ω
	Fall Time	t _f	---	3	18	μs	

*1 Current Conversion Ratio = I_C / I_F × 100% , CTR Tolerance:±3%.

7. Rank Table of Current Transfer Ratio

CTR BIN	Min (%)	Max (%)	Condition
A	80	160	$V_{CE} = 5V / I_F = 5mA, T_a=25^{\circ}C$
	30	100	$V_{CE} = 5V / I_F = 1mA, T_a=25^{\circ}C$
B	130	260	$V_{CE} = 5V / I_F = 5mA, T_a=25^{\circ}C$
	50	150	$V_{CE} = 5V / I_F = 1mA, T_a=25^{\circ}C$
C	200	400	$V_{CE} = 5V / I_F = 5mA, T_a=25^{\circ}C$
	80	300	$V_{CE} = 5V / I_F = 1mA, T_a=25^{\circ}C$
D	300	600	$V_{CE} = 5V / I_F = 5mA, T_a=25^{\circ}C$
	120	400	$V_{CE} = 5V / I_F = 1mA, T_a=25^{\circ}C$

8. Order Information

Part Number

ORPC-817XT-V-W-Z

Note

X = Lead form option (S, S2, M or none)

T = CTR Rank (A, B, C, D or none)

V = Tape and reel option (TP, TP1, TA1 or none).

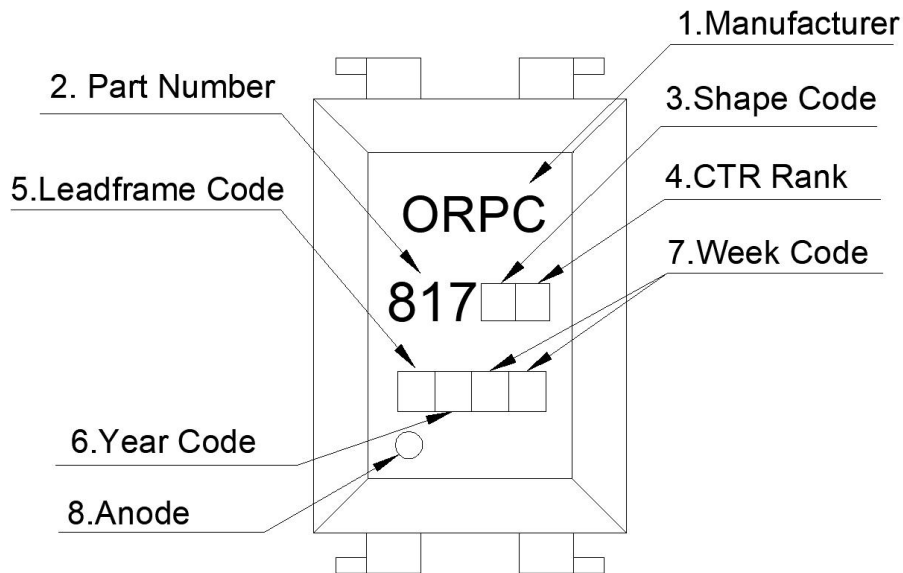
W = Lead frame option (F: Iron, C:copper)

Z = 'G' code for Halogen free (This options is not necessary).

* Halogen Free can be selected.

Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
M	Wide lead bend (0.4 inch spacing)	100 units per tube
S(TP)	Surface mount lead form (low profile) + TP tape & reel option	2000 units per reel
S(TP1)	Surface mount lead form (low profile) + TP1 tape & reel option	2000 units per reel

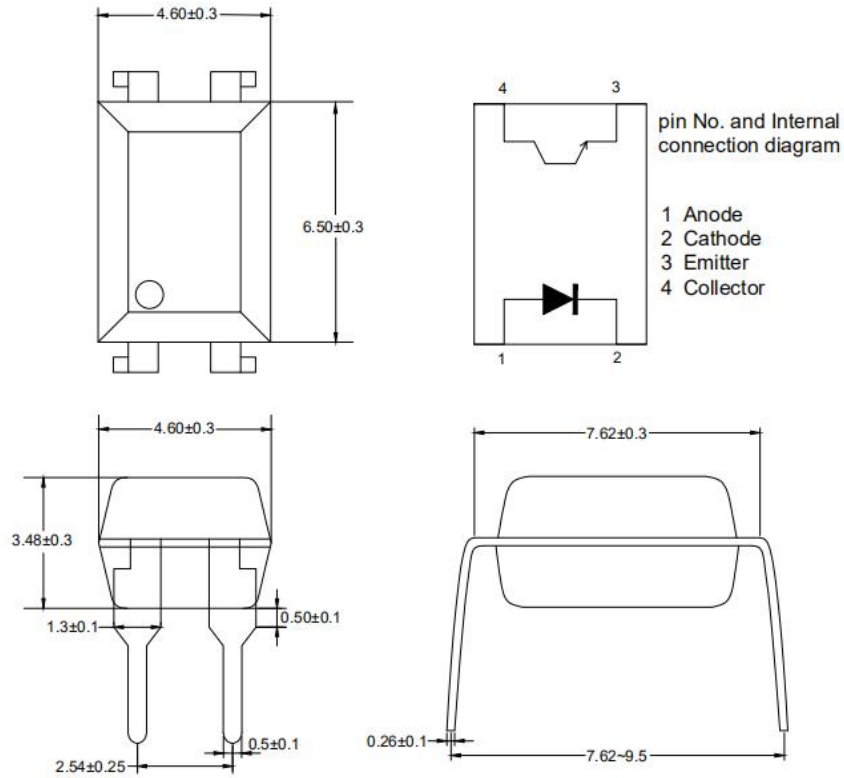
9. Naming Rule



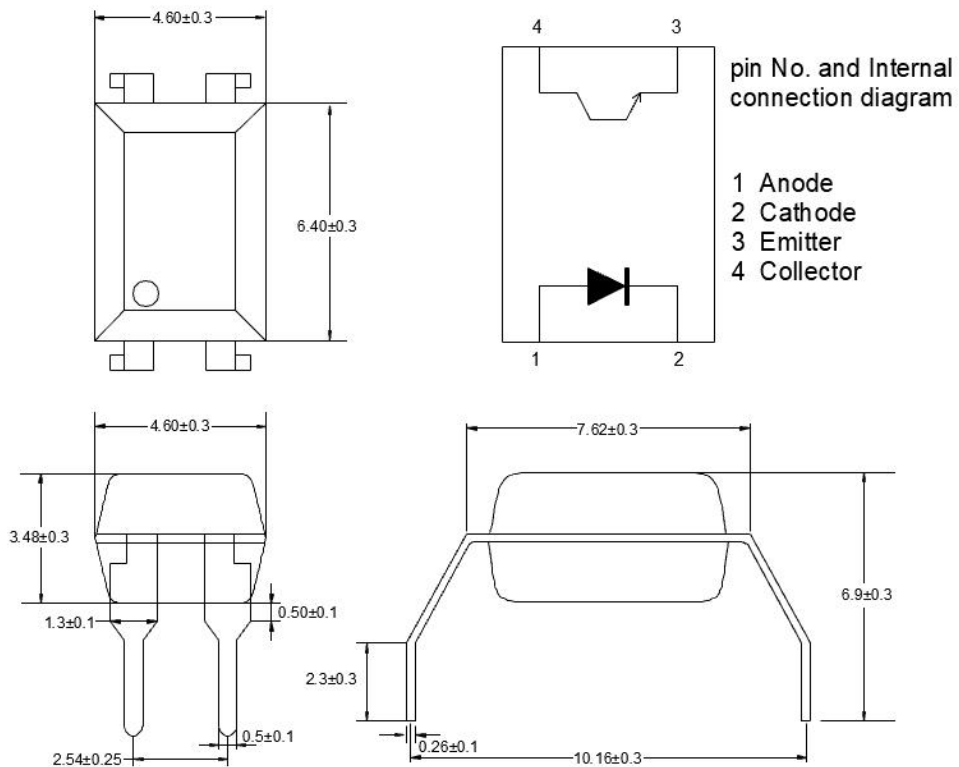
1. Manufacturer : ORIENT.
2. Part Number : 817.
3. Shape Code .
4. Rank Code : CTR Rank
5. Lead frame Code : 'F' means Iron, 'C' means Copper.
6. Year Code : '1' means '2021' and so on.
7. Week Code : 01 means the first week, 02 means the second week and so on.
8. Anode.

10. Package Dimension (Unit: mm)

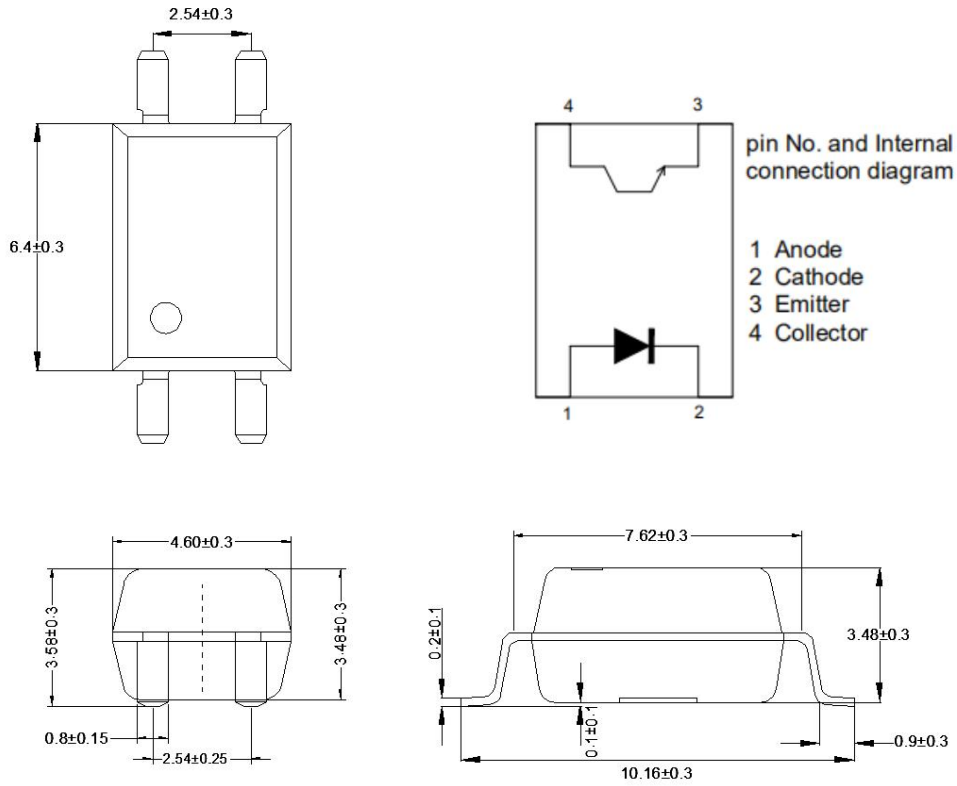
(1) ORPC-817



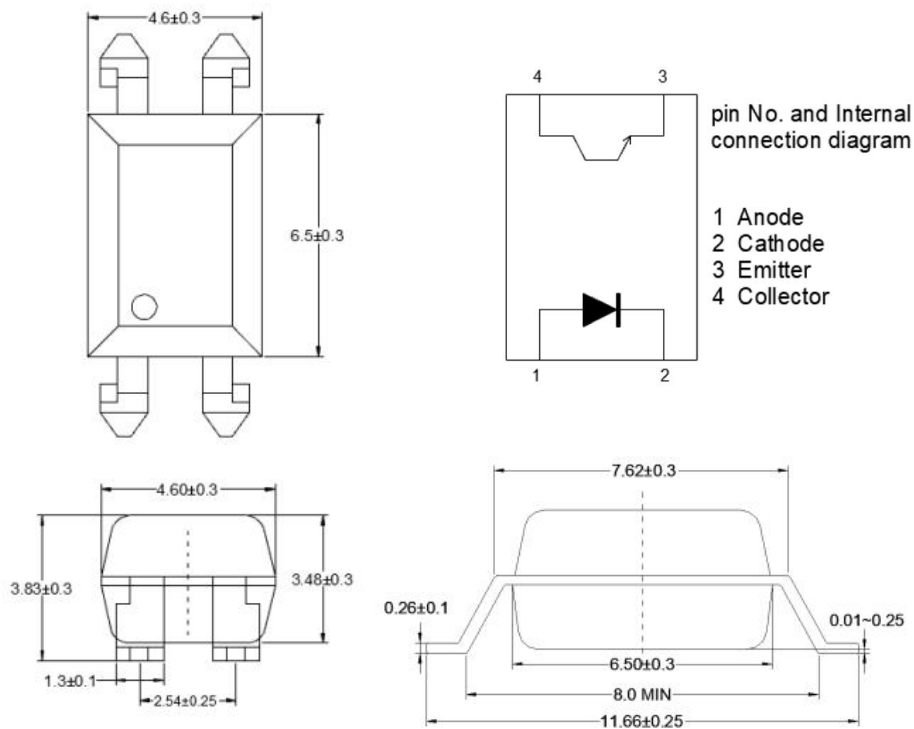
(2) ORPC-817M



(3) ORPC-817S

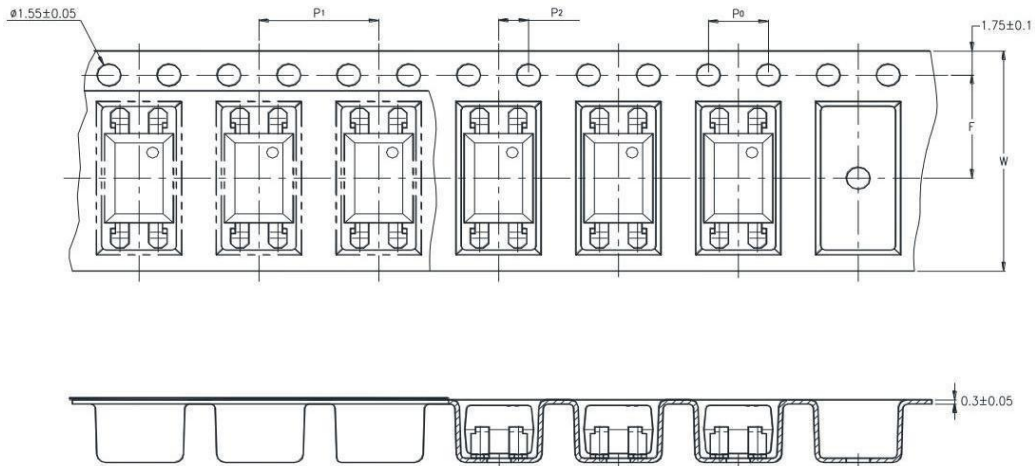


(4) ORPC-817S2

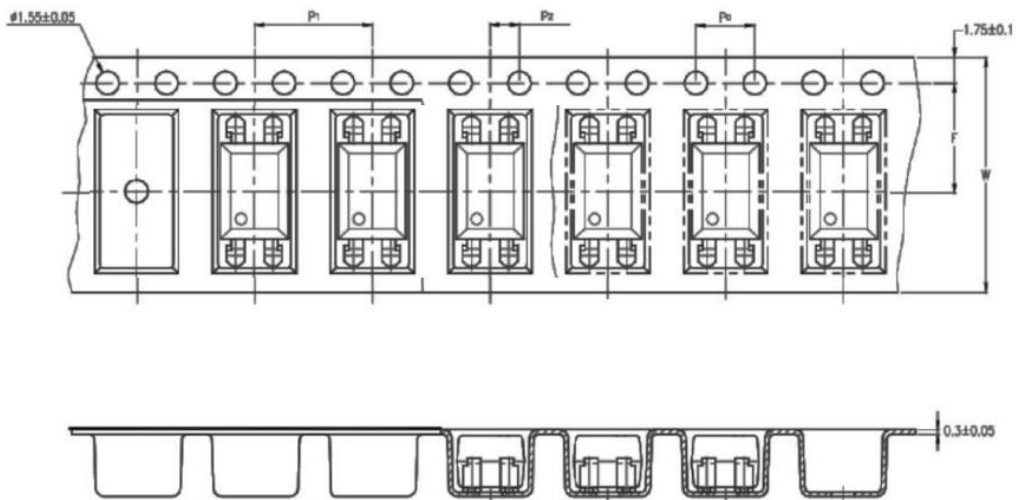


11. Taping Dimensions

(1)ORPC-817S-TP



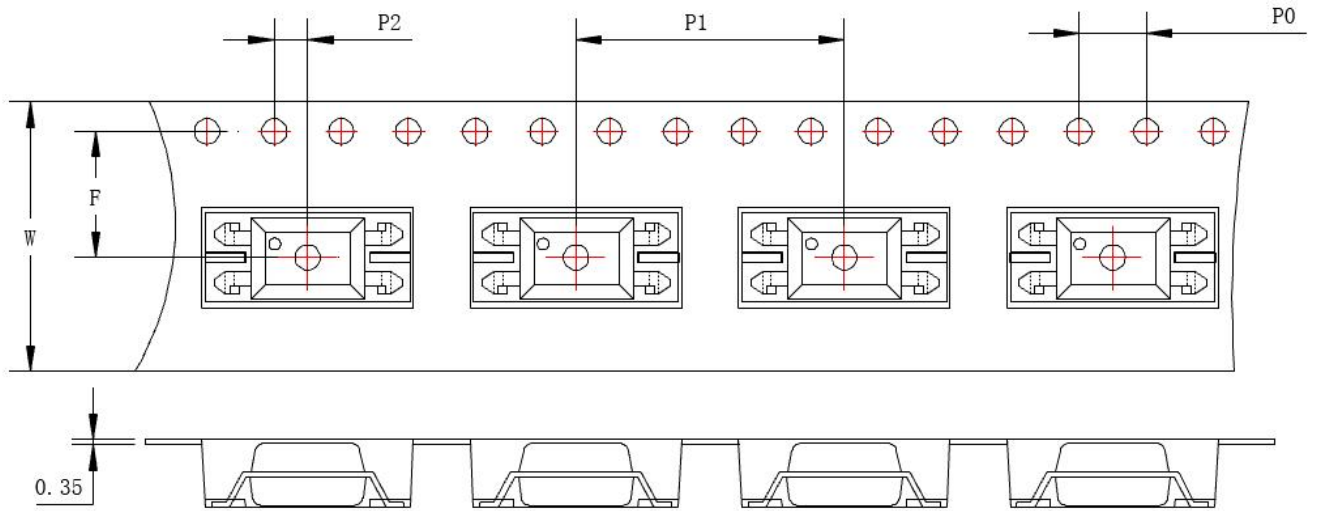
(2)ORPC-817S-TP1



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (.63)
Pitch of sprocket holes	P ₀	4±0.1 (.15)
Distance of compartment	F	7.5±0.1 (.295)
	P ₂	2±0.1 (.0079)
Distance of compartment to compartment	P ₁	8±0.1 (.472)

Package Type	TP/TP1
Quantities(pcs)	2000

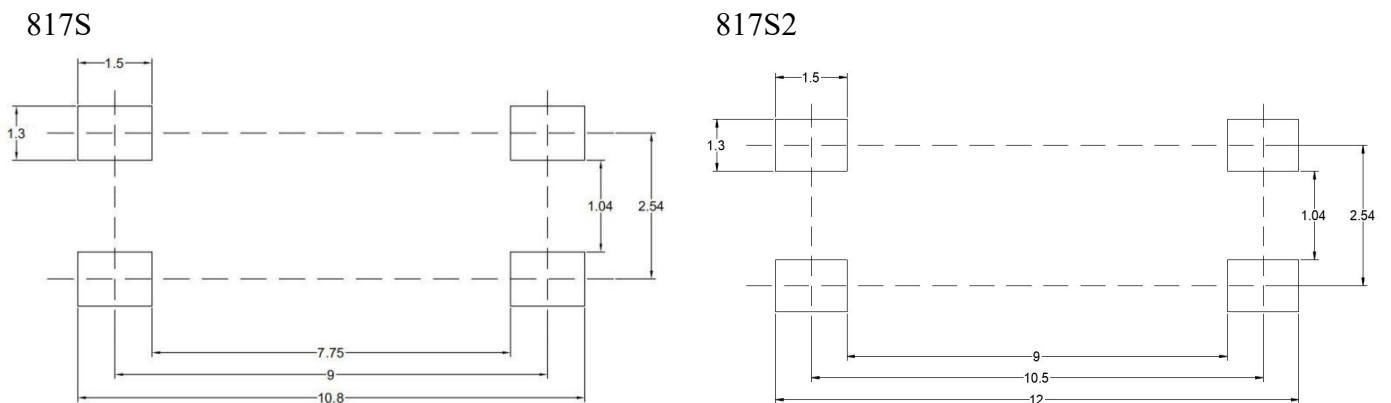
(3)ORPC-817S2-TA1



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (.63)
Pitch of sprocket holes	P ₀	4±0.1 (.15)
Distance of compartment	F	7.5±0.1 (.295)
	P ₂	2±0.1 (.0079)
Distance of compartment to compartment	P ₁	16±0.1 (.472)

Package Type	TA1
Quantities(pcs)	1000

12. Recommended Foot Print Patterns (Mount Pad) (Unit: mm)



13. Package Dimension

(1) package dimension

DIP Type

Packing Information	
Packing type	Tube
Qty per Tube	100pcs
Small box (Inner) Dimension	525*128*60mm
Large box (Outer) Dimension	545*290*335mm
The Amount per Inner Box	5,000pcs
The Amount per Outer Box	50,000pcs

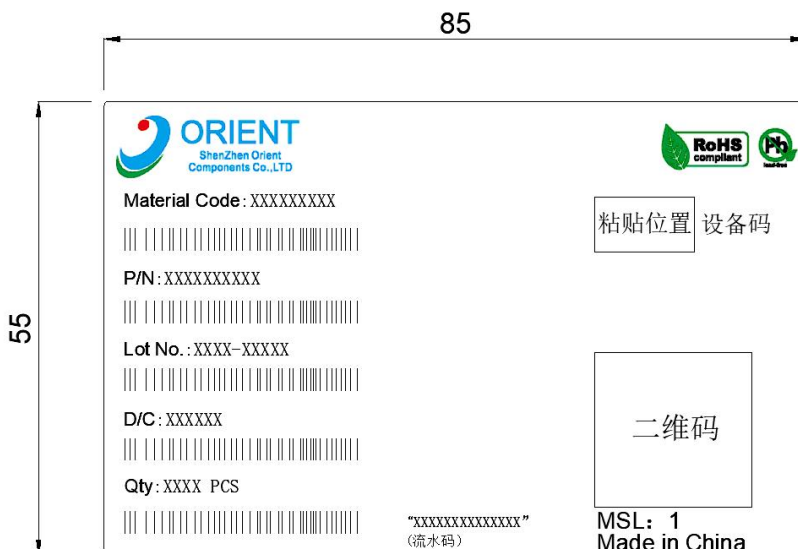
SOP-S Type

Packing Information	
Packing type	Reel type
Tape Width	16mm
Qty per Reel	2,000pcs
Small box (inner) Dimension	345*345*58.5mm
Large box (Outer) Dimension	620x360x360mm
Max qty per small box	4,000pcs
Max qty per large box	40,000pcs

SOP-S2 Type

Packing Information	
Packing type	Reel type
Tape Width	16mm
Qty per Reel	1,000pcs
Small box (inner) Dimension	345*345*58.5mm
Large box (Outer) Dimension	620x360x360mm
Max qty per small box	2,000pcs
Max qty per large box	20,000pcs

(2)Packing Label Sample



Note:

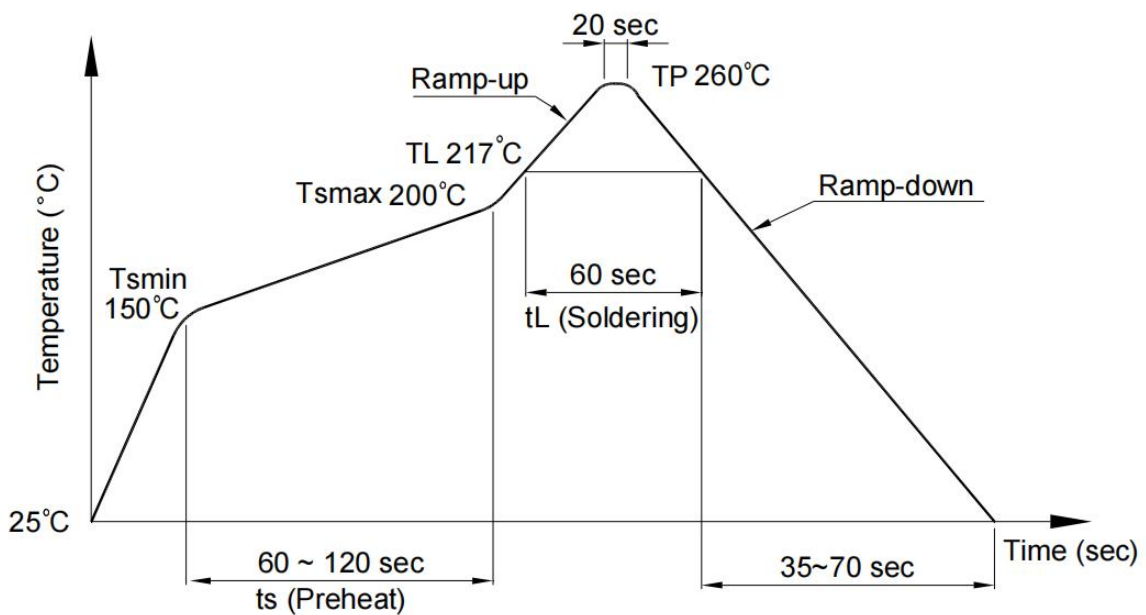
1. Material Code :Product ID.
2. P/N :Contents with "Order Information" in the specification.
3. Lot No. :Product weeks.
4. D/C :Product data.
5. Quantity :Packaging quantity.

14. Temperature Profile Of Soldering

(1).IR Reflow soldering (JEDEC-STD-020 compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

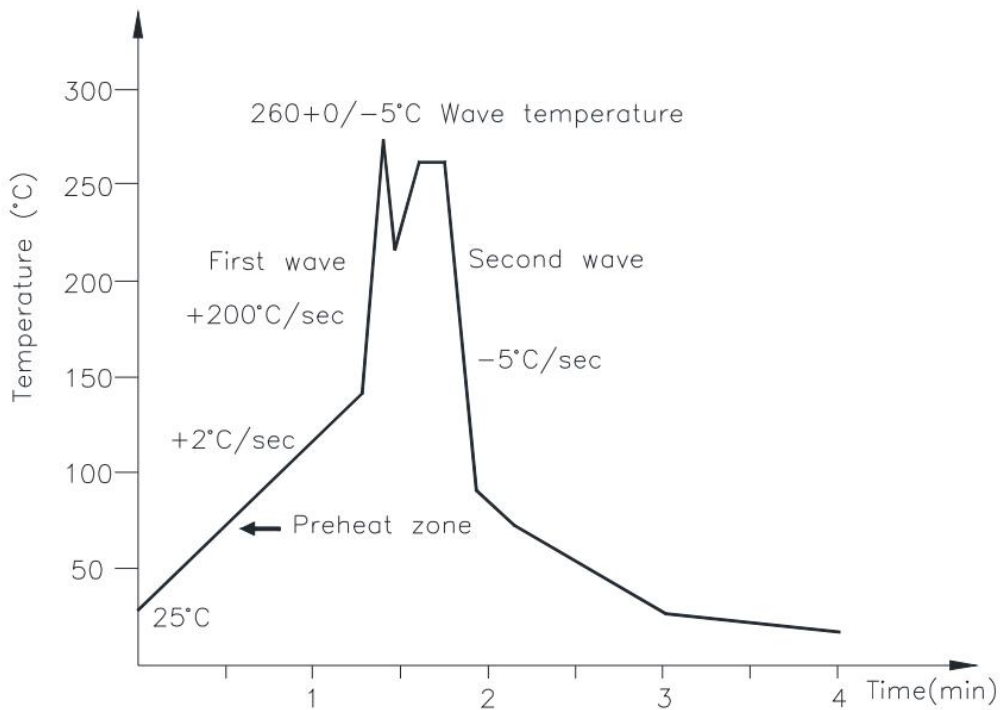
Profile item	Conditions
Preheat	
- Temperature Min (T Smin)	150°C
- Temperature Max (T Smax)	200°C
- Time (min to max) (ts)	90±30 sec
Soldering zone	
- Temperature (TL)	217°C
- Time (t L)	60 sec
Peak Temperature	260°C
Peak Temperature time	20 sec
Ramp-up rate	3°C / sec max.
Ramp-down rate from peak temperature	3~6°C / sec
Reflow times	≤3



(2).Wave soldering (JEDEC22 A111 compliant)

One time soldering is recommended within the condition of temperature.

Temperature	260+0/-5°C
Time	10 sec
Preheat temperature	25 to 140°C
Preheat time	30 to 80 sec



(3).Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature	380+0/-5°C
Time	3 sec max

15. Characteristics Curves

Fig.1 Forward current vs Ambient temperature

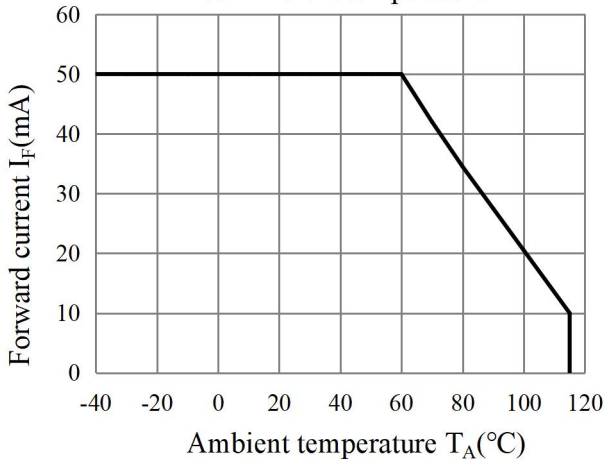


Fig.2 Collector Power Dissipation vs. Ambient temperature

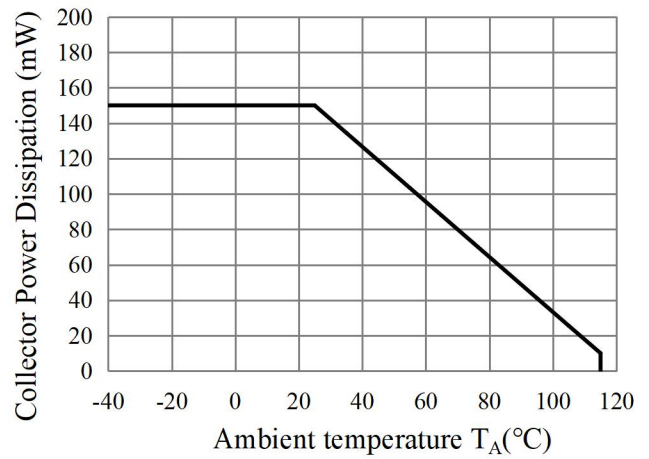


Fig.3 Forward Current vs. Forward Voltage

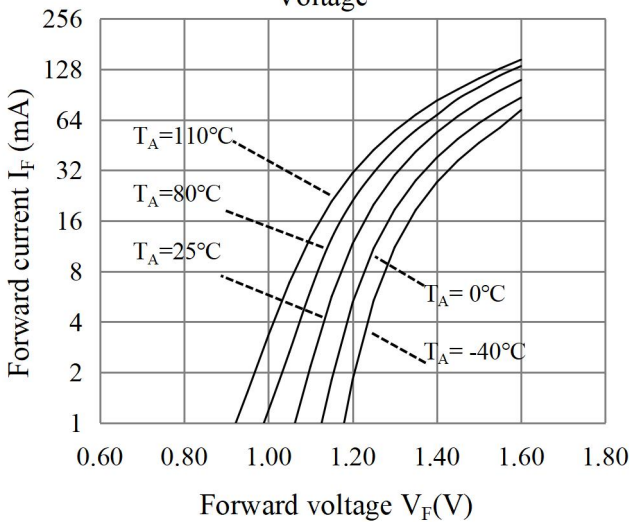


Fig.4 Collector-emitter Saturation Voltage vs. Forward Current

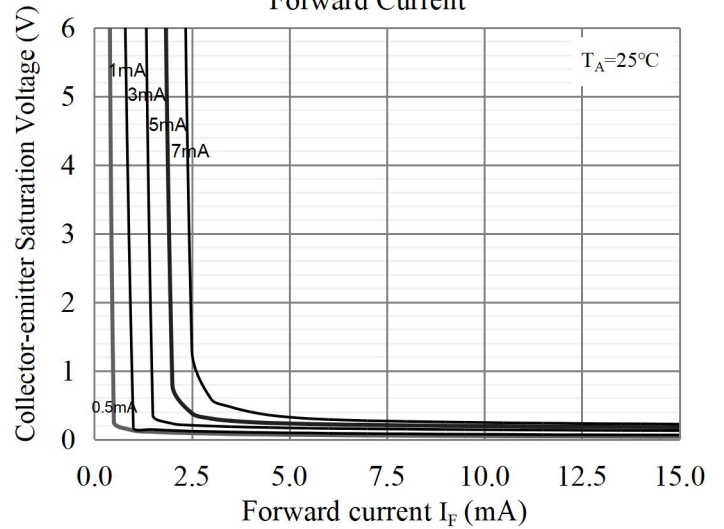


fig.5 Collector Current vs. Non-Saturated Collector Emitter Voltage

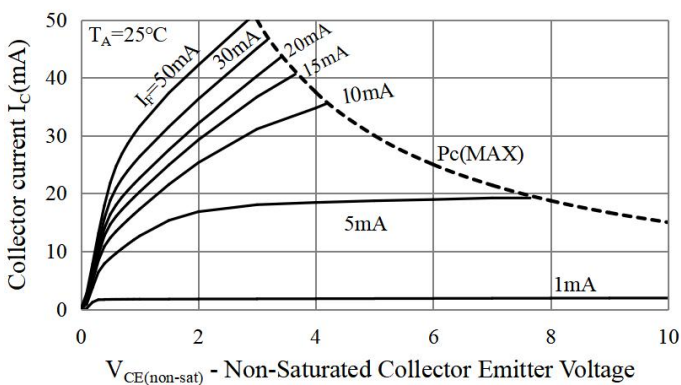


fig.6 Collector Current vs. Non-Saturated Collector Emitter Voltage

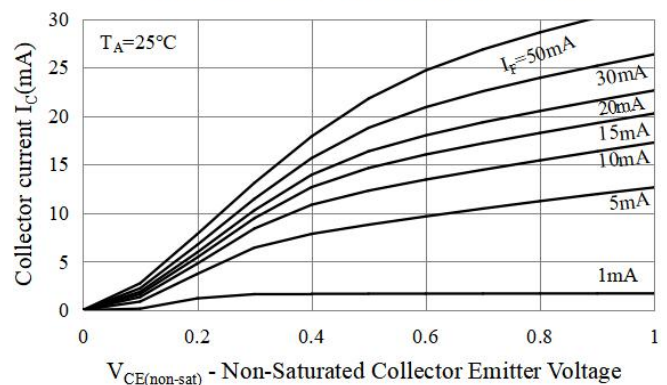


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

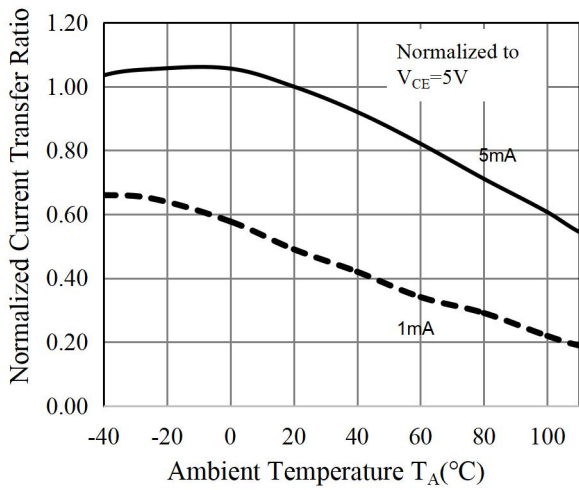


Fig.8 Relative Current Transfer Ratio vs. Ambient Temperature

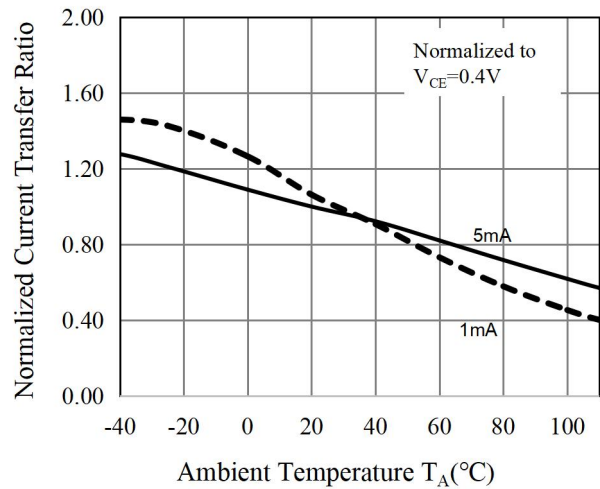


Fig.9 Forward Current vs. Current Transfer Ratio

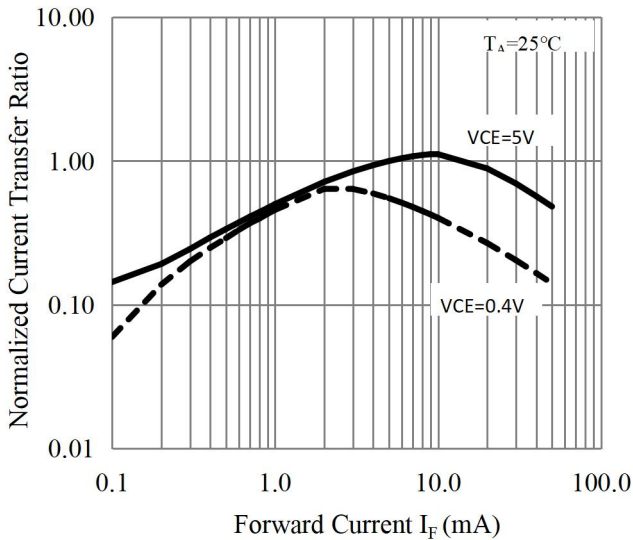


Fig.10 Collector Dark Current vs. Ambient Temperature

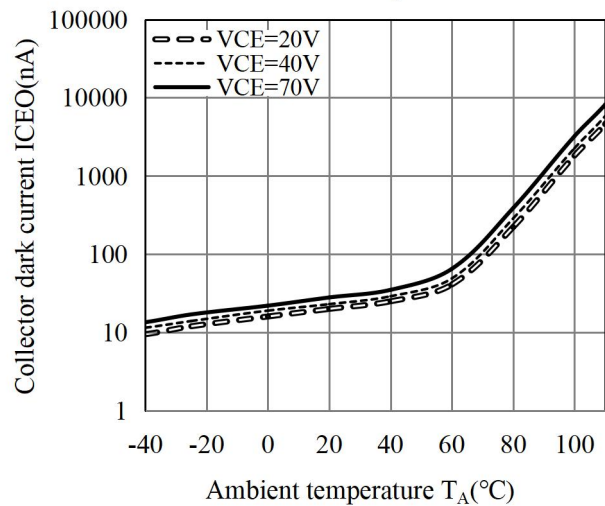


Fig.11 Collector-emitter Saturation Voltage vs. Ambient Temperature

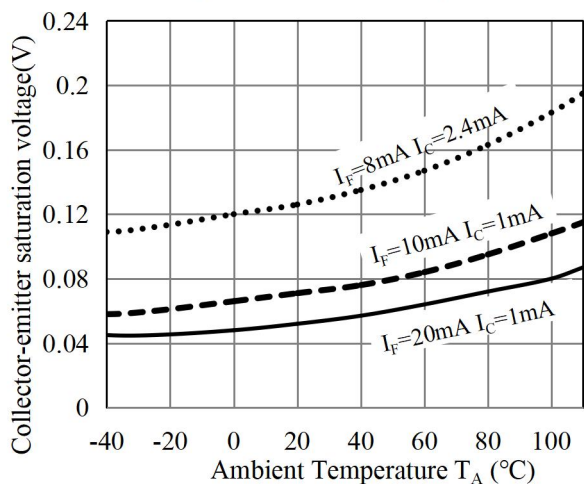


Fig.12 Switching Time vs. Load Resistance

